## Single Inverter with Open Drain Outputs

The NLV17SZ06 is a high performance single inverter with open drain outputs operating from a 1.65 to 5.5 V supply.

The Output stage is open drain with Over Voltage Tolerance. This allows the NLV17SZ06 to be used to interface 5.0 V circuits to circuits of any voltage between 0 and +7.0 V.

#### **Features**

- Tiny SOT-353 Package
- Extremely High Speed:  $t_{PD}$  2.5 ns (typical) at  $V_{CC} = 5.0 \text{ V}$
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation, CMOS Compatible
- • Over Voltage Tolerant Inputs  $V_{IN}$  may be Between 0 and 7.0 V for  $V_{CC}$  Between 0.5 and 5.5 V
- TTL Compatible Interface Capability with 5.0 V TTL Logic with  $V_{CC}$  = 2.7 V to 3.6 V
- LVCMOS Compatible
- 24 mA Output Sink Capability, Pullup may be between 0 and 7.0 V
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 20
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

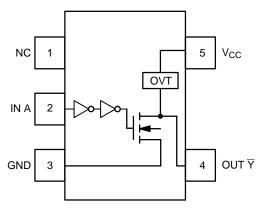


Figure 1. Pinout (Top View)

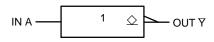


Figure 2. Logic Symbol



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SOT-353/SC70-5/SC-88A DF SUFFIX CASE 419A



**MARKING** 

LF = Specific Device Marking

M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)
\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### **PIN ASSIGNMENT**

Pin	Function
1	NC
2	IN A
3	GND
4	OUT \( \overline{Y} \)
5	V <sub>CC</sub>

#### **FUNCTION TABLE**

A Input	▼ Output
L	Z
Н	L

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### NLV17SZ06

#### **MAXIMUM RATINGS**

Symbol	Characteristics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
VI	DC Input Voltage	$-0.5 \le V_1 \le +7.0$	V
Vo	DC Output Voltage Output in Z or LOW State (Note 1)	$-0.5 \le V_O \le 7.0$	V
I <sub>IK</sub>	DC Input Diode Current V <sub>I</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>O</sub> < GND	-50	mA
I <sub>O</sub>	DC Output Sink Current	±50	mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin	±100	mA
I <sub>GND</sub>	DC Ground Current Per Ground Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
P <sub>D</sub>	Power Dissipation in Still Air	186	mW
$\theta_{JA}$	Thermal Resistance	350	°C/W
TL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias	+150	°C
I <sub>Latch-Up</sub>	Latchup Performance Above V <sub>CC</sub> and Below GND at 85°C (Note 5)	±500	mA
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD	ESD Classification  Human Body Model (Note 3)  Machine Model (Note 4)  Charged Device Model (Note 5)	Class IC Class A N/A	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Io absolute maximum rating must be observed.

2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.

- 3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	(Z or LOW State)	0	5.5	V
T <sub>A</sub>	Operating Free-Air Temperature		-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0 0	20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### NLV17SZ06

#### DC ELECTRICAL CHARACTERISTICS

			V		A = 25°	С	$-55$ °C ≤ $T_A$ ≤ 125°C		
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
I <sub>LKG</sub>	Z–State Output Leakage Current	$V_{IN} = V_{IL}$ $V_{OUT} = V_{CC}$ or GND	2.3 to 5.5			±5.0		±10.0	μΑ
V <sub>OL</sub>	Low-Level Output	I <sub>OL</sub> = 100 μA	1.65 to 5.5		0.0	0.1		0.1	V
	Voltage   V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 4 mA	1.65		0.08	0.24		0.24	
		I <sub>OL</sub> = 8 mA	2.3		0.22	0.3		0.3	
		I <sub>OL</sub> = 12 mA	2.7		0.22	0.4		0.4	
		I <sub>OL</sub> = 16 mA	3.0		0.28	0.4		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.38	0.55		0.55	
		$I_{OL} = 32 \text{ mA}$	4.5		0.42	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	$V_{IN} = 5.5 \text{ V or}$ $V_{OUT} = 5.5 \text{ V}$	0			1.0		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = 5.5 \text{ V or GND}$	5.5			1.0		10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### AC ELECTRICAL CHARACTERISTICS $t_R=t_F=2.5~\text{ns};~C_L=50~\text{pF};~R_L=500~\Omega$

				1	A = 25°	2	-55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
t <sub>PZL</sub>	Propagation Delay	$R_{L} = R_1 = 500 \Omega, C_L = 50 pF$	1.65	0.8	5.3	11.6	0.8	12.0	ns
	(Figure 3 and 4)		2.5 ± 0.2	0.8	3.0	3.6	0.8	4.1	
			3.3 ± 0.3	0.8	2.4	3.2	0.8	3.7	
			5.0 ± 0.5	0.5	2.4	3.0	0.5	3.5	
t <sub>PLZ</sub>	Propagation Delay	$R_{L=} R_{1} = 500 \Omega, C_{L} = 50 pF$	1.65	0.8	5.3	11.6	0.8	12.0	ns
	(Figure 3 and 4)		2.5 ± 0.2	0.8	2.5	3.6	0.8	4.1	
			3.3 ± 0.3	0.8	2.1	3.2	0.8	3.7	
			5.0 ± 0.5	0.5	1.2	3.0	0.5	3.5	

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	>2.5	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	4.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	10 MHz, $V_{CC}$ = 5.5 V, $V_{I}$ = 0 V or $V_{CC}$	4.0	pF

<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

#### **NLV17SZ06**

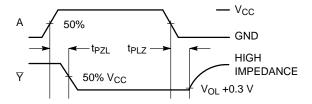
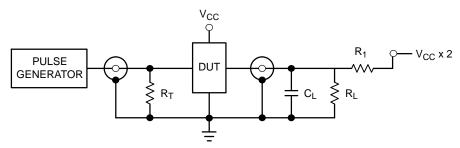


Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 4. Test Circuit

#### **DEVICE ORDERING INFORMATION**

Device Order Number	Package Type	Tape and Reel Size <sup>†</sup>
NLV17SZ06DFT2G*	SOT-353/SC70-5/SC-88A (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.



#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE L**

**DATE 17 JAN 2013** 



- TIES:
  DIMENSIONING AND TOLERANCING
  PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
  419A-01 OBSOLETE. NEW STANDARD 3.
- 419A-02.
  DIMENSIONS A AND B DO NOT INCLUDE
- MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

# -B-S D 5 PL 0.2 (0.008) M B M **SOLDER FOOTPRINT**

+++			
0.40			0.65 0.025
	<u>1.9</u> 0.0748	SCALE 20:1	$\left(\frac{\text{mm}}{\text{inches}}\right)$
OT # F 4	07450	07.45.0	

0.50 0.0197

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. CATHODE
2. EMITTER	2. EMITTER	2. N/C	2. DRAIN 1/2	2. COMMON ANODE
3. BASE	3. BASE	3. ANODE 2	3. SOURCE 1	3. CATHODE 2
4. COLLECTOR	4. COLLECTOR	4. CATHODE 2	4. GATE 1	4. CATHODE 3
4. COLLECTOR	4. COLLECTOR	4. CATHODE 2	4. GATE 1	4. CATHODE 3
5. COLLECTOR	5. CATHODE	5. CATHODE 1	5. GATE 2	5. CATHODE 4

J. GOLLLOTON	3. CATTODE	J. CATHODE I	J. GAIL 2	J. CATTODE 4
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE 1	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:	98ASB42984B	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED"	
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